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SVA / F	Properties of Gase	es and Liquids, N	nes Potentials as Dete IcGraw-Hill, Inc., Cop	ermined from ' yright 1987, p	Viscosity Data (Append .734, Index		•	
M a	at Low Density", T	ransport Phenon	nena, John Wiley & S	ons, Inc., Cop	ort; Theory of Ordinary cyright 1960, p. 508-51	3		
sur o	of Mechanical Eng	ineers, 1996, Ky	oritsu Shuppan Co.,	_td.	cations", section 2.6.4			
su s	Semiconductor Wo	orld, January 199	93, pp. 1-11, and tran	slation	SITION OF SULFUR,			
- <i>(</i>) - / *	Ken FUJITA et al., POLYMERIZED FI NO. 1, January 19	LUOROCARBO	N FILMS ON SI", Jpn.	J. Appl. Phys	TUDIES ON PYROLY . volume 34 (1995), pp	o. 304-3	06, Pa	art 1
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O A A			SMA ETCHING OF S	i and SiO₂ in	SF ₆ -O ₂ MIXTURES", J	. Appi. i	-riys. t	

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SHEET _1 OF 1

THIRD
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Ge XU et al.	
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-Any	TFTs by controlling O ₂ /Sih ₄ ratios; AM-LCD 1997; pages 87-90.									
ļ	Flow of Atoms and Molecules, 1996 (not translated)									
										
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